Preferred Device

Triacs

Silicon Bidirectional Thyristors

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required.

- Blocking Voltage to 800 Volts
- On-State Current Rating of 8.0 Amperes RMS at 100°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dv/dt 500 V/\mu s minimum at 125°C
- Minimizes Snubber Networks for Protection
- Industry Standard TO-220AB Package
- High Commutating di/dt 6.5 A/ms minimum at 125°C
- Device Marking: Logo, Device Type, e.g., MAC9D, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open) MAC9D MAC9M MAC9N	VDRM, VRRM	400 600 800	Volts
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T _C = 100°C)	IT(RMS)	8.0	Amps
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T _J = 125°C)	ITSM	80	Amps
Circuit Fusing Consideration (t = 8.3 ms)	I ² t	26	A ² sec
Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 80°C)	PGM	16	Watts
Average Gate Power (t = 8.3 ms, T _C = 80°C)	P _G (AV)	0.35	Watt
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

⁽¹⁾ VDRM and VRRM for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

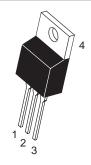


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TRIACS 8 AMPERES RMS 400 thru 800 VOLTS





TO-220AB CASE 221A STYLE 4

PIN ASSIGNMENT				
1	Main Terminal 1			
2	Main Terminal 2			
3	Gate			
4	Main Terminal 2			

ORDERING INFORMATION

Device	Package	Shipping
MAC9D	TO220AB	50 Units/Rail
MAC9M	TO220AB	50 Units/Rail
MAC9N	TO220AB	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance — Junction to Case — Junction to Ambient	R _{ÐJC} R _{ÐJA}	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

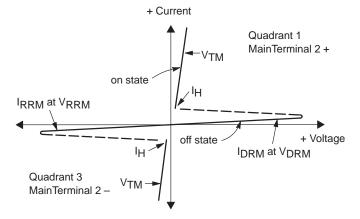
ELECTRICAL CHARACTERISTICS (T_{.J} = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Peak Repetitive Blocking Current (V_D = Rated V_{DRM} , V_{RRM} ; Gate Open) T_J = 25°C T_J = 125°C	I _{DRM} , I _{RRM}	_ _	_ _	0.01 2.0	mA
ON CHARACTERISTICS					
Peak On-State Voltage* (I _{TM} = ±11 A Peak)	VTM	_	1.2	1.6	Volts
Gate Trigger Current (Continuous dc) (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	I _{GT}	10 10 10	16 18 22	50 50 50	mA
Holding Current ($V_D = 12 \text{ V}$, Gate Open, Initiating Current = $\pm 150 \text{ mA}$)	lН	_	30	50	mA
Latching Current (V _D = 24 V, I _G = 50 mA) MT2(+), G(+); MT2(-), G(-) MT2(+), G(-)	ΙL	_ _ _	20 30	50 80	mA
Gate Trigger Voltage (V_D = 12 V, R_L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	VGT	0.5 0.5 0.5	0.69 0.77 0.72	1.5 1.5 1.5	Volts
Gate Non–Trigger Voltage (V _D = 12 V, R _L = 100 Ω , T _J = 125°C) MT2(+), G(+); MT2(+), G(-); MT2(-), G(-)	V _{GD}	0.2	_	_	Volts
DYNAMIC CHARACTERISTICS					
Rate of Change of Commutating Current; See Figure 10. (V_D = 400 V, I_{TM} = 4.4 A, Commutating dv/dt = 18 V/ μ s, Gate Open, T_J = 125°C, f = 250 Hz, No Snubber) C_L = 10 μ F L_L = 40 mH	(di/dt) _C	6.5	_	_	A/ms
Critical Rate of Rise of Off-State Voltage $(V_D = Rated\ V_{DRM}, Exponential\ Waveform, Gate\ Open,\ T_J = 125^{\circ}C)$	dv/dt	500	_	_	V/µs

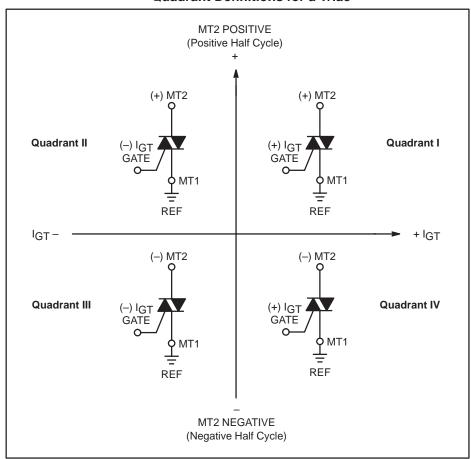
^{*}Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V _{DRM}	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
lΗ	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

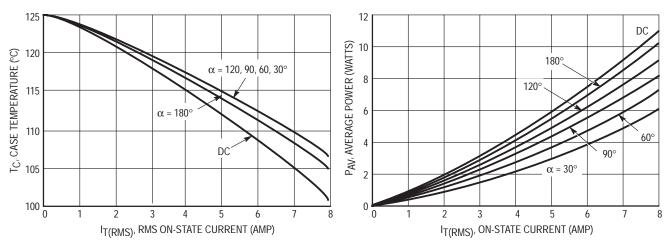
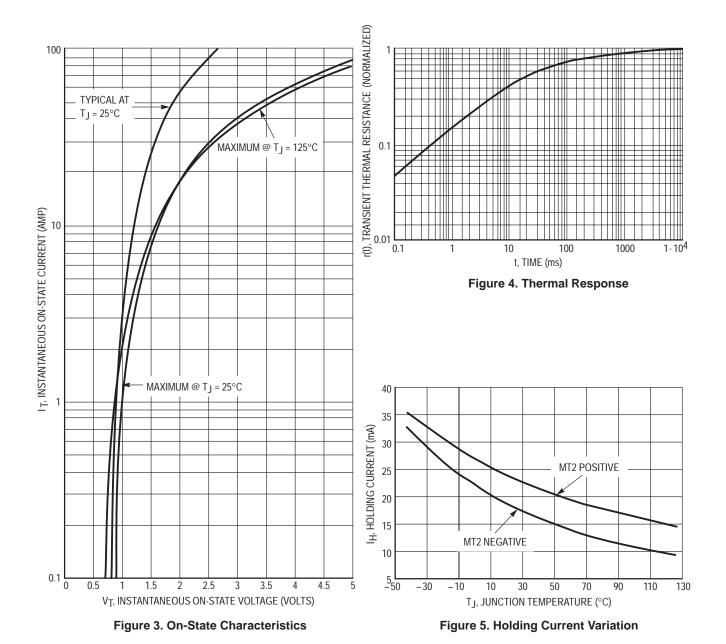


Figure 1. RMS Current Derating

Figure 2. On-State Power Dissipation



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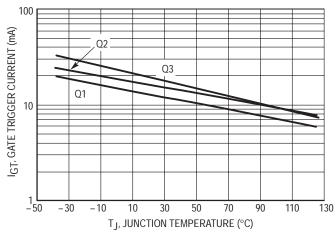


Figure 6. Gate Trigger Current Variation

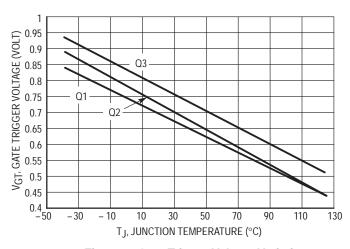


Figure 7. Gate Trigger Voltage Variation

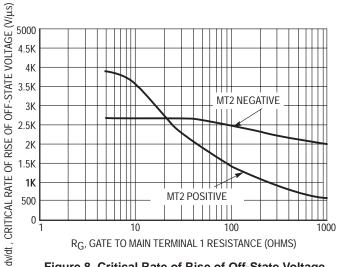


Figure 8. Critical Rate of Rise of Off-State Voltage (Exponential)

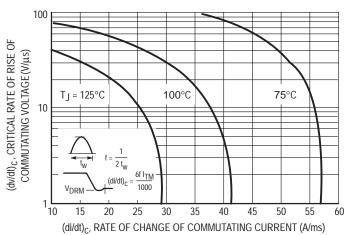
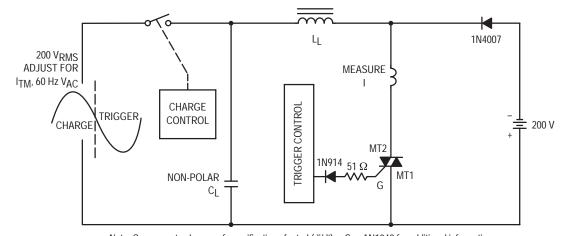


Figure 9. Critical Rate of Rise of Commutating Voltage

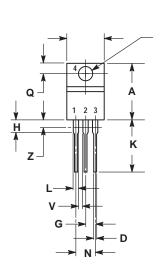


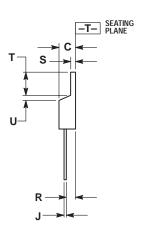
Note: Component values are for verification of rated (di/dt) $_{\mathbb{C}}$. See AN1048 for additional information.

Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)_C

PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 ISSUE Z





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 4:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. MAIN TERMINAL 2



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